

Complementary Output Hall Effect Fan Driver

❖ GENERAL DESCRIPTION

MA7201 is integrated Hall sensors with output drivers, mainly designed for electronic commutation of brush-less DC Fan. This IC is using HV BCD process internally includes the regulator, protecting diode, Hall plate, amplifier, comparator, and a pair of complementary open-Drain outputs (DO, DOB).

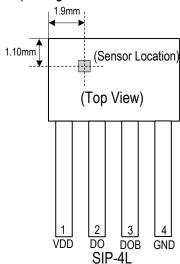
While the magnetic flux density (B) is larger than operate point (Bop), DO will turn on (low), and meanwhile DOB will turn off (high). Each output is latched until B is lower than release point (Brp), and then DO, DOB transfer each state. For DC fan application, sometimes need to test power reverse connection condition. Internal diode only protects chip-side but not for coil-side. If necessary, add one external diode to block the reverse current from coil-side.

❖ FEATURES

- On-chip Hall effect sensor with two different sensitivity and hysteresis settings
- Built-in protecting diode only for chip reverse power connecting
- Wide operating voltage range: 3.5V~20V
- Output sink current up to 0.6A
- -40°C to 85°C operating temperature range
- Low Profile SIP-4L Package(Green and Lead Free)

❖ PIN ASSIGNMENT

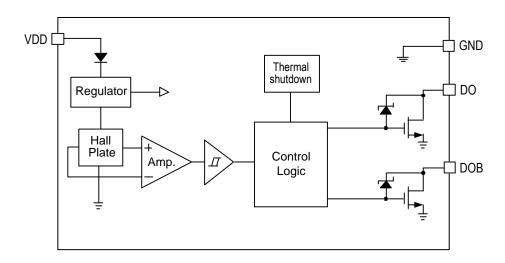
The package of MA7201 is SIP-4L; the pin assignment is given by:



Name	Description				
VDD	Supply Voltage				
DO	Output 1				
DOB	Output 2				
GND	Ground.				



❖ BLOCK DIAGRAM



RDER/MARKING INFORMATION

Order Information	Top Marking
MA7201 XX X Package Type Packing P4: SIP-4L Blank: Bag	7201 \longrightarrow Part number YYWWX \xrightarrow{X} \longrightarrow ID code:internal WW:01~52 Year:15=2015

❖ A BSOLUTE MAXIMUM RATINGS (at T_A=25°C)

Characteristics	Symbol	Rating	Unit		
Supply Voltage	Vcc	20	V		
Reverse VCC Polarity Voltage	V_{RCC}	-20	V		
Magnetic Flux Density	В	Unlimited	Gauss		
	Continuous		600		
Output Current	Hold	Ιo	900	mΑ	
	Peak (start up)		1200		
Power Dissipation	P _D	550	mW		
Storage Temperature Range			-65 to +150	°C	
Junction Temperature			150	°C	
Thermal Resistance from Junction to case			49	°C/W	
Thermal Resistance from Junction to ambient			227	°C/W	
Operating temperature Range			-40 to 85	°C	



***** ELECTRICAL CHARACTERISTICS

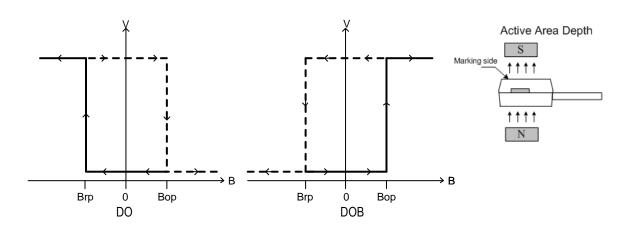
 $(V_{DD} = 12V, T_A = +25^{\circ}C, unless otherwise noted.)$

Characteristics	Symbol	Conditions	Min	Тур	Max	Units	
Supply Voltage	V_{DD}	Operating	3.5	-	20	V	
Supply current	I _{DD}	Operating	-	3.5	5	mA	
Output Leakage Current	I _{OFF}	V _{OUT} =12V	-	< 0.1	10	μΑ	
Output On resistance	R _{DS(ON)}	I _{OUT} =300mA	-	0.9	-	Ω	
Output Clamping Voltage	Vz	DO, DOB	-	32	-	V	
Thermal shutdown Temp	T _{SD}		150	-	-	°C	
Thermal Shutdown Hysteresis	T _{SH}		-	30	-	°C	
Magnetic (1mT=10 Gauss)							
Operate Point	Вор		5	30	50	Gauss	
Release Point	B _{RP}		-50	-30	-5	Gauss	
Hysteresis	B _{HYS}		-	60	-	Gauss	

Driver output vs. magnetic pole

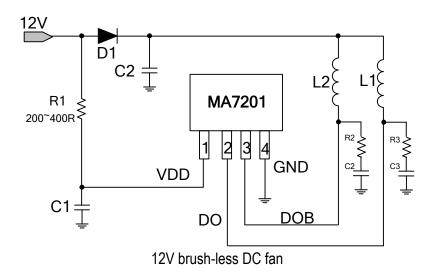
Characteristics	Test Conditions	DO	DOB
North pole	B < Brp	High	Low
South pole	B > Bop	Low	High

Note: The magnetic pole is applied facing the branded side of the package





❖ APPLICATION CIRCUIT



Note1: C2(Optional) is for power stabilization, Recommended E-Cap 2.2uF/50V and D1 (Optional) is a reverse protect diode.

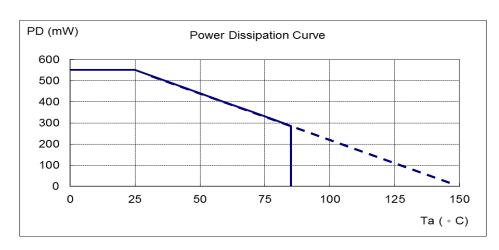
Note2: R1(1/8W 0805) and C1(100nF): Enhance the reliability during hot swap.

Note3: Recommended to use a 47 ohm for R2 & R3 and a 1uF E-Cap for C2 & C3.

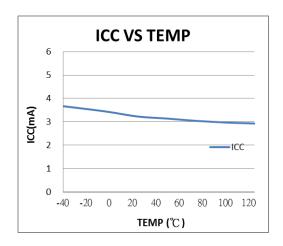
These values may need to be optimized depending on the coil used.

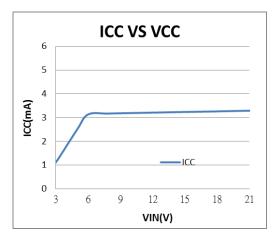
❖ PERFORMANCE CHARACTERISTICS

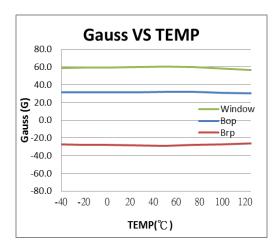
T _A (°C)	25	50	60	70	80	85	90	95	100
PD (mW)	550	440	396	352	308	286	264	242	220
T _A (°C)	105	110	115	120	125	130	135	140	150
PD (mW)	198	176	154	132	110	88	66	44	0

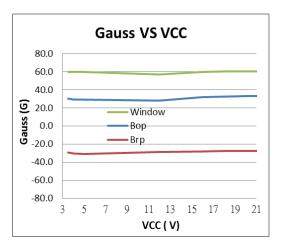


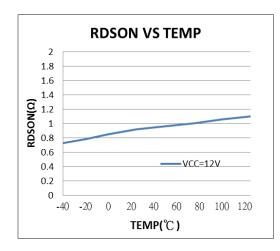


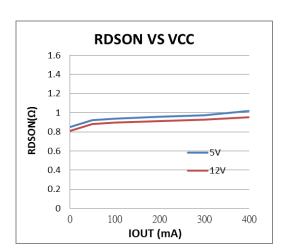














❖ PACKAGE OUTLINES

